

Data sheet acquired from Harris Semiconductor SCHS187C

January 1998 - Revised July 2003

CD54/74HC533, CD54/74HCT533, CD54/74HC563, CD74HCT563

High-Speed CMOS Logic Octal Inverting Transparent Latch, Three-State Outputs

Features

- Common Latch-Enable Control
- Common Three-State Output Enable Control
- · Buffered Inputs
- Three-State Outputs
- . Bus Line Driving Capacity
- Typical Propagation Delay = 13ns at V_{CC} = 5V,
 C_L = 15pF, T_A = 25°C (Data to Output)
- Fanout (Over Temperature Range)
 - Standard Outputs................ 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \leq 1 \mu A$ at $V_{OL},\,V_{OH}$

Description

The 'HC533, 'HCT533, 'HC563, and CD74HCT563 are high-speed Octal Transparent Latches manufactured with silicon gate CMOS technology. They possess the low power consumption of standard CMOS integrated circuits, as well as the ability to drive 15 LSTTL devices.

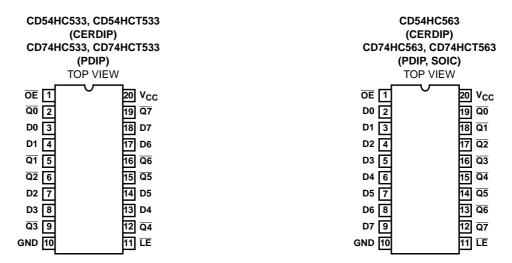
The outputs are transparent to the inputs when the latch enable ($\overline{\text{LE}}$) is high. When the latch enable ($\overline{\text{DE}}$) goes low the data is latched. The output enable ($\overline{\text{OE}}$) controls the three-state outputs. When the output enable ($\overline{\text{OE}}$) is high the outputs are in the high impedance state. The latch operation is independent of the state of the output enable.

The 'HC533 and 'HCT533 are identical in function to the 'HC563 and CD74HCT563 but have different pinouts. The 'HC533 and 'HCT533 are similar to the 'HC373 and 'HCT373; the latter are non-inverting types.

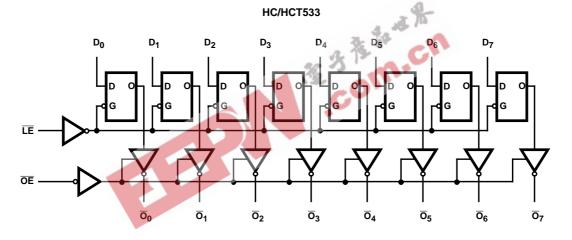
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC533F3A	-55 to 125	20 Ld CERDIP
CD54HC563F3A	-55 to 125	20 Ld CERDIP
CD54HCT533F3A	-55 to 125	20 Ld CERDIP
CD74HC533E	-55 to 125	20 Ld PDIP
CD74HC563E	-55 to 125	20 Ld PDIP
CD74HC563M	-55 to 125	20 Ld SOIC
CD74HCT533E	-55 to 125	20 Ld PDIP
CD74HCT563E	-55 to 125	20 Ld PDIP
CD74HCT563M	-55 to 125	20 Ld SOIC

Pinouts



Functional Block Diagram



TRUTH TABLE

OUTPUT ENABLE	LATCH ENABLE	DATA	Q OUTPUT
L	Н	Н	L
L	Н	L	Н
L	L	I	Н
L	L	h	L
Н	X	X	Z

H = High Voltage Level, L = Low Voltage Level, X = Don't Care, Z = High Impedance State, I = Low voltage level one set-up time prior to the high to low latch enable transition, h = High voltage level one set-up time prior to the high to low latch enable transition.

Thermal Information Absolute Maximum Ratings θ_{JA} (°C/W) DC Supply Voltage, VCC $\,$ -0.5V to 7V $\,$ Thermal Resistance (Typical, Note 1) DC Input Diode Current, I_{IK} M (SOIĆ) Package..... DC Output Diode Current, IOK For $V_O < -0.5V$ or $V_O > V_{CC}^{-1} + 0.5V$ ± 20 mA Maximum Storage Temperature Range-65°C to 150°C DC Drain Current, per Output, IO Maximum Lead Temperature (Soldering 10s).....300°C (SOIC - Lead Tips Only) DC Output Source or Sink Current per Output Pin, IO **Operating Conditions** Temperature Range, T_A -55°C to 125°C Supply Voltage Range, V_{CC} HC Types2V to 6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

4.5V...... 500ns (Max)

DC Electrical Specifications

Input Rise and Fall Time

			ST), /		25°C		-40°C T	O 85°C	-55°C T	O 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
HC TYPES													
High Level Input	V _{IH}		-	2	1.5	-	-	1.5	-	1.5	-	V	
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V	
				6	4.2	•	-	4.2	ı	4.2	-	V	
Low Level Input	V _{IL}	-	-	2	ı	ı	0.5	ı	0.5	-	0.5	V	
Voltage				4.5	-	-	1.35	ı	1.35	-	1.35	V	
				6	•	•	1.8	-	1.8	-	1.8	V	
High Level Output	V _{OH}	V _{IH} or	-0.02	2	1.9	ı	-	1.9	ı	1.9	-	V	
Voltage CMOS Loads			V _{IL}	-0.02	4.5	4.4	-	-	4.4	1	4.4	-	V
			-0.02	6	5.9	-	-	5.9	ı	5.9	-	V	
High Level Output			-6	4.5	3.98	ı	-	3.84	ı	3.7	-	V	
Voltage TTL Loads			-7.8	6	5.48	-	-	5.34	=	5.2	-	V	
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	V	
Voltage CMOS Loads		V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V	
5W65 25dd5			0.02	6	-	-	0.1	-	0.1	-	0.1	V	
Low Level Output]		6	4.5	-	-	0.26	-	0.33	-	0.4	V	
Voltage TTL Loads			7.8	6	-	-	0.26	-	0.33	-	0.4	V	
Input Leakage Current	I _I	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μА	
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μА	

DC Electrical Specifications (Continued)

			ST ITIONS			25°C	_	-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Three-State Leakage Current	-	V _{IL} or V _{IH}	V _O = V _{CC} or GND	6	-	-	±0.5	-	±5	-	±10	μА
HCT TYPES	-	-										
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	水水	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			6	4.5		3	0.26	1.0	0.33	-	0.4	V
Input Leakage Current	II	V _{CC} to GND	-	5.5	1	C	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μА
Three-State Leakage Current		V _{IL} or VIH	V _O = V _{CC} or GND	5.5	-	-	±0.5	-	±5	-	±10	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	Δl _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS
D0 - D7	0.15
ΙĒ	0.30
ŌĒ	0.55

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., $360\mu A$ max at $25^{0}C.$

^{2.} For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

Prerequisite For Switching Specifications

		TEST	v _{cc}		25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	_										
LE Pulse Width	t _W	-	2	80	-	-	100	1	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
Set-up Time Data to LE	t _{SU}	-	2	50	-	-	65	-	75	-	ns
			4.5	10	-	-	13	-	15	-	ns
			6	9	-	-	11	-	13	-	ns
Hold Time, Data to LE	t _H	-	2	35	-	-	45	-	55	-	ns
(533)			4.5	7	-	-	9	-	11	-	ns
			6	6	-	-	8	-	7	-	ns
Hold Time, Data to LE	t _H	-	2	4	-	-	4	-	4	-	ns
(563)			4.5	4	-	-	4	-	4	-	ns
			6	4	-	-	4	-	4	-	ns
HCT TYPES	•	•			700	40					
LE Pulse Width	t _w	-	4.5	16	a-79	F 3.	20		24	-	ns
Set-up Time Data to LE	t _w	-	4.5	10	(D)	3	13	-	15	-	ns
Hold Time, Data to LE (533)	t _H		4.5	8	e C) W.	10	-	12	-	ns
Hold Time, Data to LE (563)	t _H		4.5	5 🦸		-	5	-	5	-	ns

Switching Specifications Input t_r , $t_f = 6$ ns

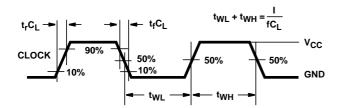
	TEST 25°C		°C	-40°C TO 85°C	-55°C TO 125°C			
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
HC TYPES								
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	165	205	250	ns
Data to Qn (HC533)			4.5	-	33	41	50	ns
			6	-	28	35	43	ns
		C _L = 15pF	5	13	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	150	190	225	ns
Data to Qn (HC563)			4.5	-	30	38	45	ns
			6	-	26	33	38	ns
		C _L = 15pF	5	12	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	175	220	265	ns
LE to Qn (HC533)			4.5	-	35	44	53	ns
(1111)			6	-	30	37	45	ns
		C _L = 15pF	5	14	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	165	205	250	ns
LE to Qn (HC563)			4.5	-	33	41	50	ns
,			6	-	28	35	43	ns
		C _L = 15pF	5	13	-	-	-	ns

Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

		TEST		25	°C	-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
Enable Times	t _{PZH,} t _{PZL}	C _L = 50pF	2	-	150	190	225	ns
(HC533)			4.5	-	30	38	45	ns
			6	-	26	33	38	ns
		C _L = 15pF	5	12	-	-	-	ns
Disable Times	t _{PHZ} , t _{PLZ}	C _L = 50pF	2	-	150	190	225	ns
(HC533)			4.5	-	30	38	45	ns
			6	-	26	33	38	ns
		C _L = 15pF	5	12	-	-	-	ns
Enable and Disable Times	t _{PZH} , t _{PZL} ,	C _L = 50pF	2	-	150	190	225	ns
(HC563)	^t PHZ, ^t PLZ		4.5	-	30	38	45	ns
			6	-	26	33	38	ns
		C _L = 15pF	5	12	-	2-	-	ns
Input Capacitance	Cl	-	-	-	10	10	10	pF
Three-State Output Capacitance	CO	-	-	5	20	20	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}		5	42	344.	-	-	pF
HCT TYPES								
Propagation Delay, Data to Qn	t _{PLH} , t _{PHL}	$C_L = 50pF$	4.5	-	34	43	51	ns
(HC/HCT533)		$C_L = 15pF$	5	14	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	30	38	45	ns
Data to Qn (HC/HCT563)		C _L = 15pF	5	12	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	38	48	57	ns
LE to Qn (HC/HCT533)		C _L = 15pF	5	16	-	-	-	ns
Propagation Delay,	t _{PZL} , t _{PZH}	C _L = 50pF	4.5	-	35	44	53	ns
LE to Qn (HC/HCT563)		C _L = 15pF	5	14	-	-	-	ns
Enable Times	t _{PLZ} , t _{PZH}	C _L = 50pF	4.5	-	35	44	53	ns
(HC/HCT533)		C _L = 15pF	5	14	-	-	-	ns
Disable Times	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	30	38	45	ns
(HC/HCT533)		C _L = 15pF	5	12	-	-	-	ns
Enable and Disable Times	t _{PZH} , t _{PZL} ,	C _L = 50pF	4.5	-	35	44	53	ns
(HC/HCT563)	t _{PHZ} , t _{PLZ}	C _L = 15pF	5	14	-	-	-	ns
Input Capacitance	C _I	-	-	-	10	10	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	42	-	-	-	pF

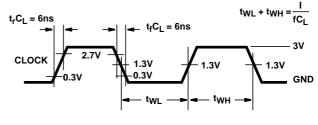
- 3. $C_{\mbox{\scriptsize PD}}$ is used to determine the no-load dynamic power consumption, per latch.
- 4. P_D (total power per latch) = $C_{PD} \ V_{CC}^2 \ f_i + \Sigma \ C_L \ V_{CC}^2 \ f_o$ where f_i = Input Frequency, f_o = Output Frequency, C_L = Output Load Capacitance, C_C = Supply Voltage.

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

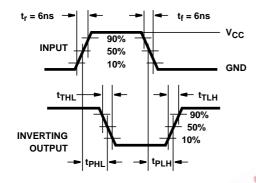


FIGURE 3. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

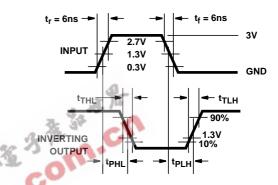


FIGURE 4. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

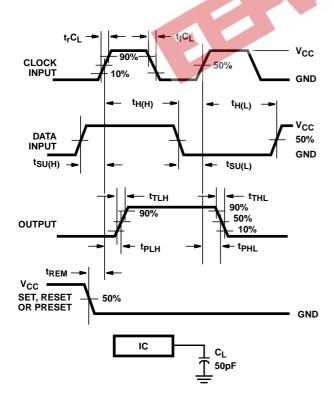


FIGURE 5. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

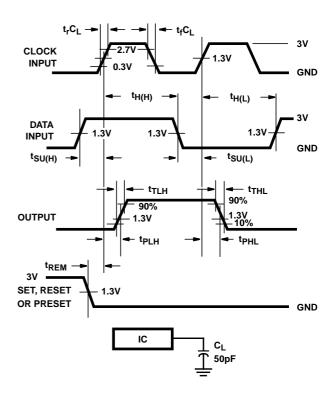
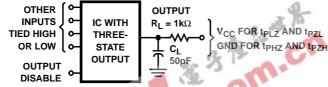


FIGURE 6. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

Test Circuits and Waveforms (Continued) t_f -3V OUTPUT v_{cc} OUTPUT DISABLE **DISABLE** 50% 0.3 10% GND GND t_{PZL} t_{PZL} t_{PLZ} → t_{PLZ} → **OUTPUT LOW OUTPUT LOW** 50% TO OFF TO OFF 1.3V 10% 10% ◆ t_{PHZ} ◆ ← t_{PZH} ← t_{PHZ} ← <- t_{PZH} → 90% 90% **OUTPUT HIGH OUTPUT HIGH** TO OFF TO OFF OUTPUTS -OUTPUTS OUTPUTS OUTPUTS **OUTPUTS OUTPUTS ENABLED** ENABLED DISABLED **ENABLED** DISABLED ENABLED FIGURE 7. HC THREE-STATE PROPAGATION DELAY FIGURE 8. HCT THREE-STATE PROPAGATION DELAY **WAVEFORM WAVEFORM**



NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 9. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT



PACKAGE OPTION ADDENDUM

10-May-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-8606201RA	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
5962-8681301RA	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC533F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC563F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT533F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD74HC533E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC533EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC563E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC563EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC563M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC563ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC563MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT533E	ACTIVE	PDIP	N	20	2 0	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT533EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT563E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT563EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT563M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT563ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT563MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

10-May-2007

retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

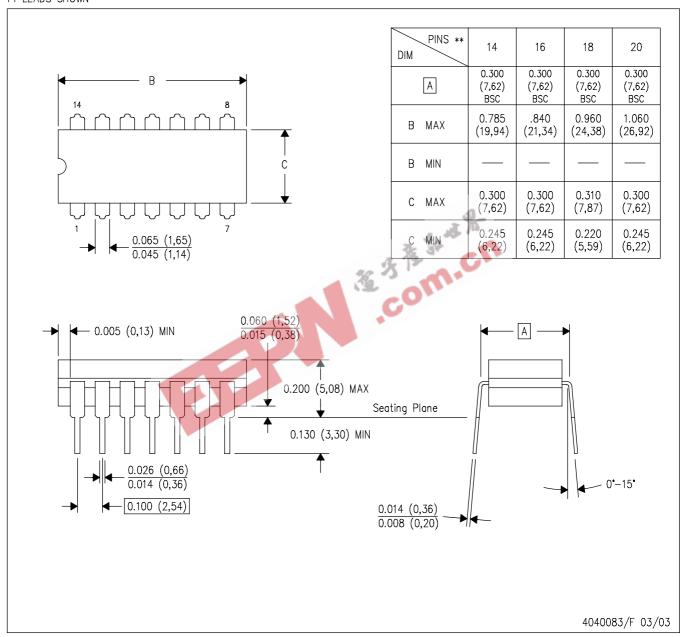
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



14 LEADS SHOWN

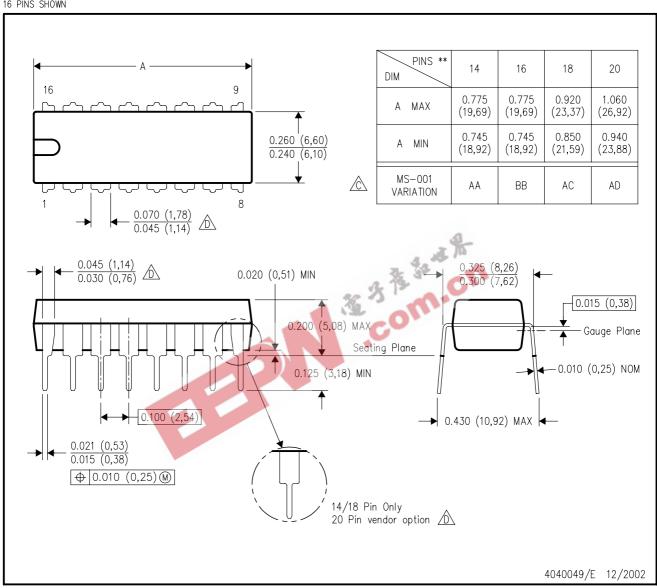


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- $E. \quad \text{Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.} \\$

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

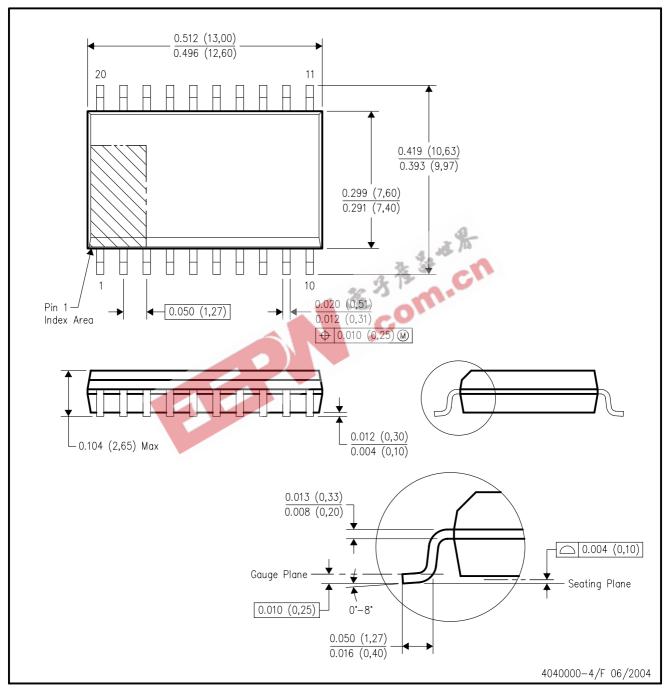
16 PINS SHOWN



- All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.

DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	<u>dsp.ti.com</u>	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
Low Power Wireless	www.ti.com/lpw	Telephony	www.ti.com/telephony
		Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2007, Texas Instruments Incorporated